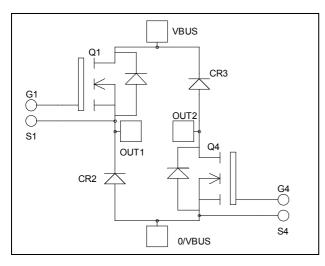
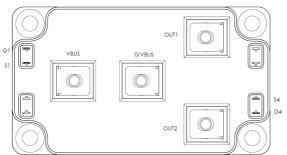


# Asymmetrical - bridge MOSFET Power Module

$$\begin{split} V_{DSS} &= 200 V \\ R_{DSon} &= 8 m \Omega \text{ typ @ Tj} = 25^{\circ} C \\ I_D &= 208 A \text{ @ Tc} = 25^{\circ} C \end{split}$$





### Application

- Welding converters
- Switched Mode Power Supplies
- Switched Reluctance Motor Drives

#### **Features**

- Power MOS 7<sup>®</sup> MOSFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V
T	Continuous Drain Current	$T_c = 25$ °C	208	
$I_{D}$	Continuous Diani Current	$T_c = 80$ °C	155	A
$I_{DM}$	Pulsed Drain current	832		
$V_{GS}$	Gate - Source Voltage	±30	V	
R <sub>DSon</sub>	Drain - Source ON Resistance		10	mΩ
$P_{\mathrm{D}}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		781	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		100	A
$E_{AR}$	Repetitive Avalanche Energy		50	m I
$E_{AS}$	Single Pulse Avalanche Energy	e Pulse Avalanche Energy		mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
T	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$ $T_j = 25^{\circ}C$			375	μА
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 160V$ $T_j = 125^{\circ}C$			1500	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 104A$		8	10	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 5mA$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±150	nA

**Dynamic Characteristics** 

·	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		14.4		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		4.66		nF
$C_{rss}$	Reverse Transfer Capacitance	f=1MHz		0.29		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		280		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{Bus} = 100V$		106		пC
$Q_{gd}$	Gate – Drain Charge	$I_D = 208A$		134		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		32		
$T_{r}$	Rise Time	$\begin{aligned} &V_{GS} = 15V \\ &V_{Bus} = 133V \\ &I_D = 208A \\ &R_G = 2.5\Omega \end{aligned}$		64		ns
$T_{d(off)}$	Turn-off Delay Time			88		
$T_{\mathrm{f}}$	Fall Time			116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 133V$ $I_D = 208A$ , $R_G = 2.5\Omega$		1698		1
$E_{\text{off}}$	Turn-off Switching Energy			1858		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		1872		
E <sub>off</sub>	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 208A, R_G = 2.5\Omega$		1972		μJ

## Diode ratings and characteristics

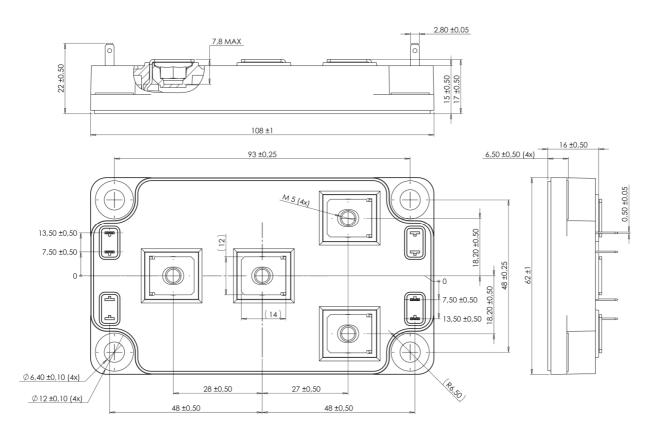
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			200			V
$I_{RM}$	Maximum Reverse Leakage Current	$1 V_p = 200V$	$T_j = 25^{\circ}C$			250	^
1 <sub>RM</sub>			$T_j = 125$ °C			600	μΑ
$I_F$	DC Forward Current		$T_c = 75^{\circ}C$		200		Α
	Diode Forward Voltage	$I_F = 200A$			1	1.1	
$V_{\rm F}$		$I_F = 400A$			1.4		V
		$I_F = 200A$	$T_j = 125$ °C		0.9		
+	Reverse Recovery Time		$T_j = 25$ °C		60		ns
$t_{rr}$		$I_F = 200A$ $V_R = 133V$	$T_{j} = 125^{\circ}C$		110		115
Q <sub>rr</sub>	Reverse Recovery Charge	$di/dt = 400A/\mu s$	$T_j = 25$ °C		400		nC
			$T_{j} = 125^{\circ}C$		1680		IIC.



### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance		Transistor			0.16	°C/W
MthJC			Diode			0.29	C/ VV
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	°C
$T_{STG}$	Storage Temperature Range			-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

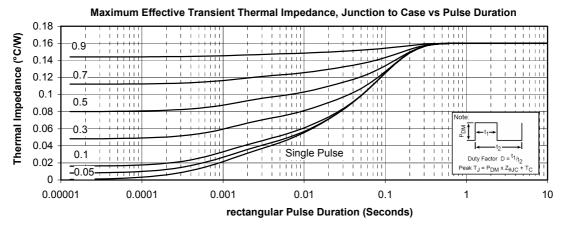
### SP6 Package outline (dimensions in mm)



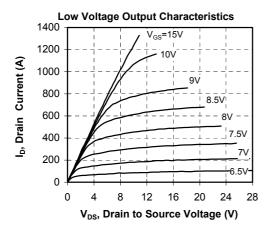
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

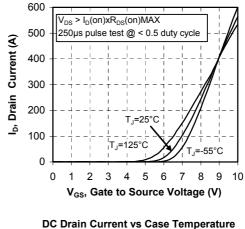


### **Typical Performance Curve**

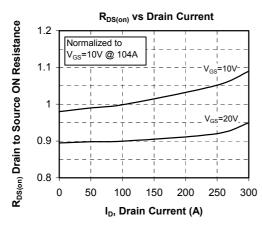


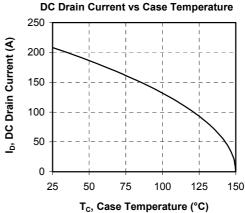
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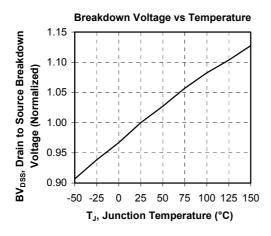
**Transfert Characteristics** 

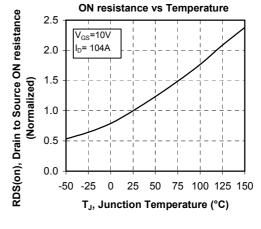


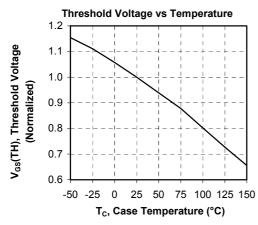


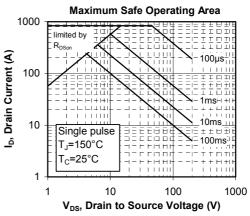
4 - 7

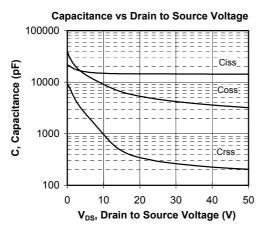


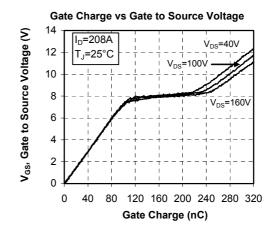








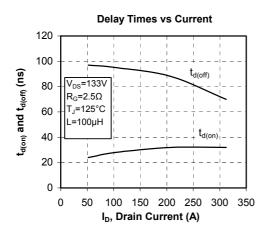


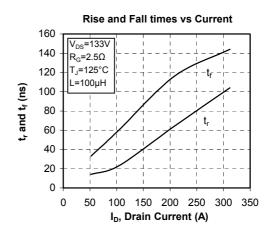


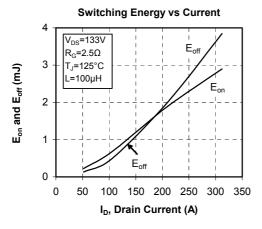
5 - 7

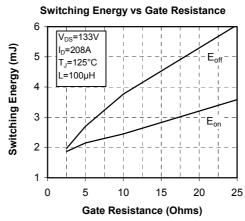
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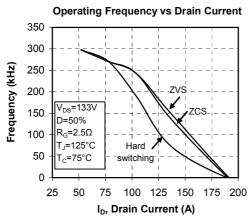


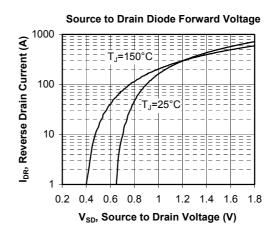














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